

IGBT Chopper

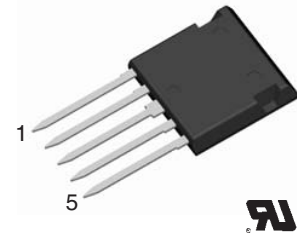
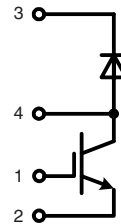
in ISOPLUS i4-PAC™

$$I_{C25} = 38 \text{ A}$$

$$V_{CES} = 600 \text{ V}$$

$$V_{CE(sat) \text{ typ.}} = 1.9 \text{ V}$$

Preliminary data



IGBT		
Symbol	Conditions	Maximum Ratings
V_{CES}	$T_{VJ} = 25^{\circ}\text{C to } 150^{\circ}\text{C}$	600 V
V_{GES}		± 20 V
I_{C25}	$T_C = 25^{\circ}\text{C}$	38 A
I_{C90}	$T_C = 90^{\circ}\text{C}$	24 A
I_{CM} V_{CEK}	$V_{GE} = \pm 15 \text{ V}; R_G = 10 \Omega; T_{VJ} = 125^{\circ}\text{C}$ RBSOA, Clamped inductive load; $L = 100 \mu\text{H}$	110 A
		V_{CES}
t_{SC} (SCSOA)	$V_{CE} = V_{CES}; V_{GE} = \pm 15 \text{ V}; R_G = 10 \Omega; T_{VJ} = 125^{\circ}\text{C}$ non-repetitive	10 μs
P_{tot}	$T_C = 25^{\circ}\text{C}$	125 W

Symbol	Conditions	Characteristic Values ($T_{VJ} = 25^{\circ}\text{C}$, unless otherwise specified)			
		min.	typ.	max.	
$V_{CE(sat)}$	$I_C = 25 \text{ A}; V_{GE} = 15 \text{ V}; T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		1.9 2.2	2.4 V V	
$V_{GE(th)}$	$I_C = 0.7 \text{ mA}; V_{GE} = V_{CE}$	3		5 V	
I_{CES}	$V_{CE} = V_{CES}; V_{GE} = 0 \text{ V}; T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		0.04	0.04 mA mA	
I_{GES}	$V_{CE} = 0 \text{ V}; V_{GE} = \pm 20 \text{ V}$			200 nA	
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off}	Inductive load, $T_{VJ} = 125^{\circ}\text{C}$ $V_{CE} = 300 \text{ V}; I_C = 25 \text{ A}$ $V_{GE} = \pm 15 \text{ V}; R_G = 10 \Omega$		30 50 320 70	ns ns ns ns	
				1.1 0.6	mJ mJ
C_{ies}		$V_{CE} = 25 \text{ V}; V_{GE} = 0 \text{ V}; f = 1 \text{ MHz}$		1.6	nF
Q_{Gon}		$V_{CE} = 300 \text{ V}; V_{GE} = 15 \text{ V}; I_C = 15 \text{ A}$		140	nC
R_{thJC}		with heatsink compound			1.0 K/W
R_{thJH}			2.0		K/W

Features

- NPT IGBT
 - low saturation voltage with positive temperature coefficient
 - low switching losses
 - wide safe operating area
- HiPerFRED™ diode
 - fast reverse recovery
 - low operating forward voltage
 - low leakage current
- ISOPLUS i4-PAC™ package
 - isolated back surface
 - low coupling capacity between pins and heatsink
 - enlarged creepage towards heatsink
 - application friendly pinout
 - low inductive current path
 - high reliability
 - industry standard outline
 - UL registered E 72873

Applications

- medium frequency power supplies
 - boost chopper for power factor correction
 - transformer primary switch
- drives: supply of
 - switched reluctance machines
 - armature or excitation winding of DC machines
 - excitation winding of synchronous machines

IXYS reserves the right to change limits, test conditions and dimensions.

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Diode

Symbol	Conditions	Maximum Ratings	
V_{RRM}	$T_{VJ} = 25^{\circ}\text{C}$ to 150°C	600	V
I_{F25}	$T_C = 25^{\circ}\text{C}$	30	A
I_{F90}	$T_C = 90^{\circ}\text{C}$	16	A

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
V_F	$I_F = 25\text{ A}; T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$	2.5	2.8	V
		1.7		V
I_R	$V_R = V_{RRM}; T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$	0.1	0.1	mA mA
I_{RM} t_{rr}	$I_F = 15\text{ A}; di_F/dt = -400\text{ A}/\mu\text{s}; T_{VJ} = 125^{\circ}\text{C}$ $V_R = 300\text{ V}; V_{GE} = 0\text{ V}$	7		A
		50		ns
R_{thJC} R_{thJH}	with heatsink compound	4.6	2.3	K/W K/W

Component

Symbol	Conditions	Maximum Ratings	
T_{VJ}		-55...+150	$^{\circ}\text{C}$
T_{stg}		-55...+125	$^{\circ}\text{C}$
V_{ISOL}	$I_{ISOL} \leq 1\text{ mA}; 50/60\text{ Hz}$	2500	V~
F_C	mounting force with clip	20...120	N

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
C_p	coupling capacity between shorted pins and mounting tab in the case		40	pF
$d_{S^*d_A}$	pin - pin	1.7		mm
$d_{S^*d_A}$	pin - backside metal	5.5		mm
Weight			9	g

Dimensions in mm (1 mm = 0.0394")

